

# Effects of plasma spatial profile on conversion efficiency of laser-produced plasma sources for EUV lithography

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**Abstract.** Extreme ultraviolet (EUV) lithography devices that use laser-produced plasma (LPP), discharge-produced plasma (DPP), and hybrid devices need to be optimized to achieve sufficient brightness with minimum debris generation to support the throughput requirements of high-volume manufacturing lithography exposure tools with a long lifetime. Source performance, debris mitigation, and reflector system are all critical to efficient EUV collection and component lifetime. Enhanced integrated models continue to be developed using the High Energy Interaction with General Heterogeneous Target Systems (HEIGHTS) computer package to simulate EUV photon emission, debris generation, and transport in both single and multiple laser beam interaction systems with various targets. A new Center for Materials under Extreme Environments (CMUXE) was recently established to benchmark HEIGHTS models for various EUV-related issues. The models being developed and enhanced were used to study the effect of plasma hydrodynamics evolution on the EUV radiation emission for planar and spherical geometry of a tin target and explain the higher conversion efficiency of a planar target in comparison to a spherical target. HEIGHTS can study multiple laser beams, various target geometries, and pre-pulses to optimize EUV photon production. Recent CMUXE and other experimental results are in good agreement with HEIGHTS simulation. © 2009 Society of Photo-Optical Instrumentation Engineers. [DOI: 10.1117/1.3224901]

Subject terms: extreme ultraviolet (EUV) lithography; laser-produced plasma (LPP); discharge-produced plasma (DPP); photon transport; magnetohydrodynamic (MHD); High Energy Interaction with General Heterogeneous Target Systems (HEIGHTS); Center for Materials under Extreme Environments (CMUXE).

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## 1 Introduction

Laser-produced plasma (LPP) devices are recently becoming more popular as the source of EUV production for the advanced lithography. Spitzer et al.<sup>1</sup> performed an experimental study of laser irradiation on several materials for generating EUV radiation and showed that tin is one of the most promising target materials for EUV production around 13.5-nm wavelength. The experiment also examined the dependence of the conversion efficiency (CE) on the intensity, wavelength, and pulse width of the laser beam.

Recently, LPP processes for the optimization of EUV production were studied using several target materials (such as xenon, lithium, and tin),<sup>2–4</sup> different target geometry and composition (solid, liquid, cluster grains, etc.),<sup>5,6</sup> and various laser radiation parameters (power density, wavelength, and pulse duration).<sup>7</sup> Numerous experiments and computer simulations were made to increase the EUV radiation power. Such analysis also included the use of pre-pulses for formation of the optimum plasma plume for EUV production during the main laser pulse.<sup>8–10</sup> The optimization of target geometry for efficient laser energy absorption was analyzed using liquid-jets,<sup>11</sup> droplets with tuning of droplet

size and laser spot size ratio,<sup>12</sup> and the use of planar targets with various thicknesses.<sup>13</sup> The implementation of mass-limited Sn-doped targets for the production of optically thin plasma and minimization of tin debris was also studied.<sup>13,14</sup> The influence of the spatial plasma effects using multilaser systems for better plasma confinement<sup>15</sup> and the uniformity of spherical target heating by multiple laser beams have indicated potential significant enhancement of EUV production.<sup>16</sup> Recent experimental and theoretical efforts<sup>9,17,18</sup> show the importance of the hydrodynamic effects during plasma evolution on EUV generation. These studies observed an increase in EUV emission near the target surface located close to the laser spot or in the location of the colliding plasma plumes. This effect is believed to be due to the geometrical confinement/containment of motion of the heated plasma, i.e., the density of the hot plasma increases in such locations with an optimum balance of the plasma density/temperature for the EUV production.

Enhanced and integrated models are being developed using the High Energy Interaction with General Heterogeneous Target Systems (HEIGHTS) computer package<sup>15,19,20</sup> to simulate plasma evolution, EUV emission, and debris generation with mitigation/transport in single, multiple, and colliding plasmas. A new Center for Materials under Extreme Environments (CMUXE) was recently established at

Purdue University to benchmark HEIGHTS models against LPP-designed experiments using various Nd:YAG and CO<sub>2</sub> lasers. The models being developed and enhanced include, for example, new ideas and parameters of multiple laser beams in different geometrical configurations and with different pre-pulses to maximize EUV production. Another recent idea being pursued to enhance the production of EUV is to collide two plasma streams together. However, the study of the EUV generation in colliding plasma becomes more difficult because of the complex multidimensional character of the hydrodynamic and radiation transport problem of the two moving plasma streams. Our objective in this study is to use the integrated HEIGHTS package to benchmark recent experiments and to explore ways of maximizing the EUV radiation power.

## 2 Mathematical and Physical Model

In general, to construct comprehensive and efficient integrated models, the plasma formation and motion is solved using the set of four conservation laws—mass, momentum, energy, and magnetic field—in two-temperature approximation.<sup>18</sup> The final hydrodynamic equation set for LPP devices in matrix form can be described in the following form:

$$\frac{\partial \mathbf{U}}{\partial t} + \frac{1}{r} \frac{\partial}{\partial r} [r \mathbf{F}(\mathbf{U})] + \frac{\partial \mathbf{P}(\mathbf{U})}{\partial r} + \frac{\partial \mathbf{G}(\mathbf{U})}{\partial z} = \mathbf{\Omega}, \quad (1)$$

where the hydrodynamic fluxes are

$$\mathbf{U} = \begin{bmatrix} \rho \\ \rho v^r \\ \rho v^z \\ e_h \\ e_i \end{bmatrix}, \quad \mathbf{F}(\mathbf{U}) = \begin{bmatrix} \rho v^r \\ \rho v^r v^r \\ \rho v^z v^r \\ v^r (e_h + p_h) \\ v^r (e_i + p_i) \end{bmatrix},$$

$$\mathbf{P}(\mathbf{U}) = \begin{bmatrix} 0 \\ p_h \\ 0 \\ 0 \\ 0 \end{bmatrix}, \quad \mathbf{G}(\mathbf{U}) = \begin{bmatrix} \rho v^z \\ \rho v^r v^z \\ \rho v^z v^z + p_h \\ v^z (e_h + p_h) \\ v^z (e_i + p_i) \end{bmatrix}, \quad (2)$$

and the dissipative terms are combined in the source  $\mathbf{\Omega}$ , given as

$$\mathbf{\Omega} = \begin{bmatrix} 0 \\ 0 \\ 0 \\ Q_{e,th} + Q_{i,th} + Q_{las} + Q_{rad} \\ Q_{i,th} + Q_{ei} \end{bmatrix}. \quad (3)$$

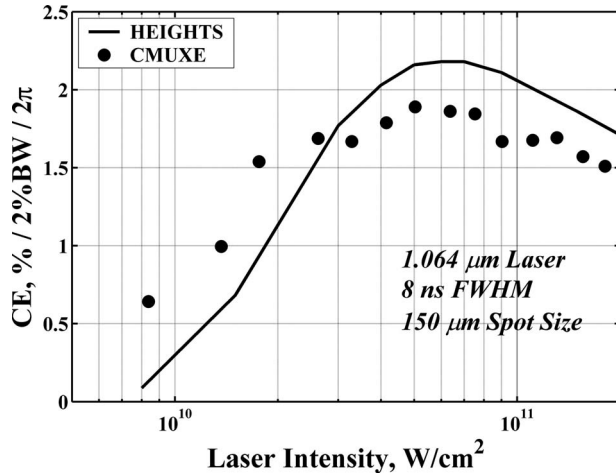
Here,  $Q_{e,th}$  is the electron heat conduction,  $Q_{i,th}$  is the ion heat conduction,  $Q_{rad}$  is the radiation power, and  $Q_{ei}$  is the electron-ion interaction. We use Gaussian units unless indicated otherwise. The conservative form of the initial equations allows the use of the total variation diminishing method in the Lax-Friedrich formulation (TVD-LF)<sup>21</sup> for the solution of the convective stage given by Eq. (1). The

numerical scheme for the TVD-LF method applied to the cylindrical symmetry case was described in Ref. 22. Following the splitting method, the  $Q$ -terms in Eq. (3) are calculated separately with the second (dissipative) stage of the HEIGHTS solver and are used as correctors for the main TVD-LF solution.<sup>15</sup> An implicit numerical scheme with sparse matrix linear solvers is used for calculating the terms  $Q_{e,th}$  and  $Q_{i,th}$  (Refs. 19 and 23). The electron-ion interaction term  $Q_{ei} = 3(m_e n_e / m_i \tau_e)(k_B T_e - k_B T_i)$  is calculated for each hydrodynamic step and used as input in the right side of Eq. (1), where  $m$  is the mass;  $n_e$  and  $\tau_e$  are electron concentration and the relaxation time, respectively;  $e$  is the electron charge; and  $k_B$  is the Boltzmann constant. Detailed description of the HEIGHTS 3-D Monte Carlo radiation transport model is given in Ref. 18.

Ideally, the laser absorption by a target should be treated in two phases: first by the cold, unperturbed solid/liquid target and then by the target having an evolving plasma layer above the remaining solid/liquid target. Most of the hydrodynamics codes developed for infrared, visible, or UV laser interaction consider the plasma creation as instantaneous, at least compared to the driving laser duration. In this approximation, the laser interacts only with the expanding plasma because the beam is reflected at the critical density, which is typically about a hundred times lower than the solid density. In reality, a sharp distinguished boundary does not exist between these two phases. This becomes important because of the complex hydrodynamic flows near the target surfaces, where we should take into account the various energy input from laser radiation, i.e., absorption/reflection in solid/liquid target, absorption/reflection in target vapor, and absorption/reflection in plasma layer. Because the production of the initial EUV radiation area above the target surface consumes part of the laser beam energy and part of main pulse duration, the final efficiency of the LPP device increases with decreasing the time needed for such a preparation stage. This entire process includes gradual decreasing of laser absorption in the cold material and increasing absorption in the hot plasma. It is also important to take into account the reabsorption of laser radiation in the evolving plasma after the reflection from the liquid target surface. For accurate modeling of the previously described processes, we used the available experimental optical properties for laser reflection from liquid tin.<sup>24,25</sup> The reflection coefficient can be derived from this data as

$$k_{ref} = \frac{(n-1)^2 + k^2}{(n+1)^2 + k^2}, \quad (4)$$

where  $k$  and  $n$  are real and imaginary parts of the refractive index  $\tilde{n} = n + ik$ . To model laser absorption in vapor material, we used the approximation given in Ref. 26. As shown here, one of the main features of the collision-induced absorption is a quadratic dependence of the absorption coefficient on the density (for our case, this corresponds to the pair collisions) and a weak dependence on the temperature.<sup>27</sup> Based on this model, we calculated the absorption coefficient for the target vapor up to 0.7 eV and fitted the dependence between the experimental data for the liquid target<sup>24,25</sup> and the bremsstrahlung coefficient given by<sup>28</sup>



**Fig. 1** Dependence of the conversion efficiency on laser intensity both experimentally (CMUXE laboratory) and in computer simulation (HEIGTS package).

$$k_{abs}^{las} = \frac{16\pi Z n_e^2 e^6 \ln \Lambda(\nu)}{3c \nu^2 (2\pi m_e k_B T_e)^{3/2} (1 - \nu_p^2/\nu^2)^{1/2}}, \quad (5)$$

and to be scaled as

$$k_{abs} \sim \rho^2 T_e^{1/2}, \quad (6)$$

where  $e$ ,  $n_e$ ,  $m_e$ ,  $T_e$  are the electron charge, concentration, mass, and temperature, respectively;  $Z$  is the normalized ionic charge;  $\nu$  is the frequency of laser light;  $\nu_p = (n_e e^2 / \pi m_e)^{1/2}$  is the plasma frequency;  $k_B$  is the Boltzmann constant; and  $\rho$  is the plasma density. The Coulomb logarithm is given by

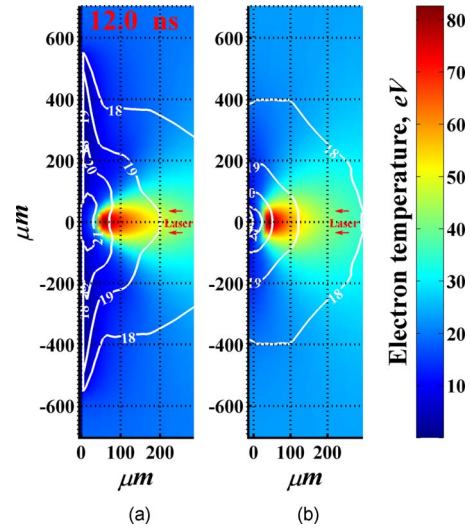
$$\ln \Lambda = \ln \left\{ \frac{3}{2} \left[ \frac{(k_B T_e)^3}{\pi m_e} \right]^{1/2} \frac{1}{Z e^3} \right\}. \quad (7)$$

### 3 Modeling Results and Discussion

To study the spatial hydrodynamic effects of spherical and planar targets on the EUV production, we modeled laser interaction with both a tin droplet and a slab target. Similar laser parameters were used in both cases, i.e., 1.064- $\mu\text{m}$  laser wavelength with 70- $\mu\text{m}$  spot size and 8-ns (full width at half maximum) duration. The diameter of the droplet was chosen to be two times larger than the laser spot size to allow efficient utilization of the laser energy, and the target can still be considered as spherical.

We compared the HEIGTS integrated modeling with the experimental data obtained in our new CMUXE laboratory. Laser beams with 8-ns duration and 150- $\mu\text{m}$  spot size on a planar target were used in both the experiment and for the HEIGTS simulation. The dependence of the CE on laser beam intensity is shown in Fig. 1 and demonstrates a good agreement with the models in both the magnitudes and the trends.

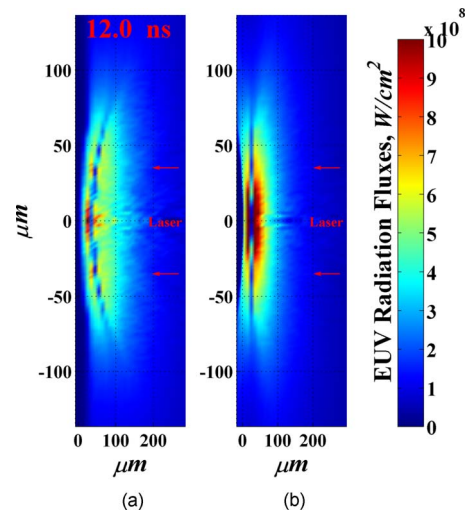
One of the main goals of this study is to determine the role of the hydrodynamic evolution and confinement processes as the potential cause for the differences in the CE between the planar and spherical targets. HEIGTS showed that planar targets provide greater geometrical



**Fig. 2** Electron temperature and density (white contours) distributions in planar (a) and droplet (b) target geometries.

plasma confinement in comparison to the spherical case. This hydrodynamic geometrical confinement prevents the plasma from quickly escaping from the EUV production zone. Figure 2 shows the electron temperature and density distributions at 4 ns after the peak of the laser beam with an intensity of  $5 \times 10^{11}$  W/cm<sup>2</sup> (FWHM) irradiated the target surface. The target surface is located in all cases near the zero point. The plasma near the target surface with electron density of around  $10^{20}$  cm<sup>-3</sup> and electron temperature of  $\sim 30$  eV forms the most productive EUV radiation area for these conditions. As shown in Fig. 3, a significant part of the emitted photons is absorbed around this area in the denser zone (close to the target surface) or in the more hot areas. The EUV radiation fluxes have larger values in surrounding regions.

The HEIGTS Monte Carlo model for radiation transport simulation permits us to determine the location and intensity of the photon source for EUV output in  $2\pi$  sr



**Fig. 3** Radiation fluxes in the EUV range for planar (a) and droplet (b) target geometries.

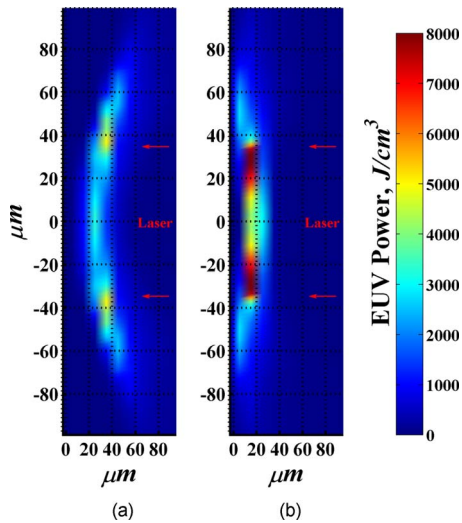


Fig. 4 Location and intensity of the EUV power collected during 20 ns in  $2\pi$  sr in planar (a) and droplet (b) target geometries.

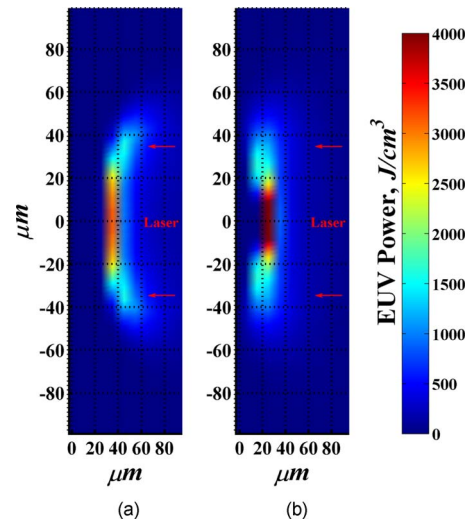


Fig. 6 Location and intensity of the collected EUV power during 20 ns in  $2\pi$  sr in planar (a) and droplet (b) target geometries.

(Fig. 4). The shape of the EUV source area corresponds to the shape of the optimum plasma plume for photon production and depends on the area of the absorbing plasma. Figure 4 illustrates the source of EUV photons collected during 20 ns with laser pulse width 8 ns (FWHM).

As shown earlier, Figs. 2–4 correspond to an intense laser heating of  $5 \times 10^{11}$  W/cm<sup>2</sup>. This analysis shows that the effective plasma confinement in the case of high laser energy input causes the plasma to overheat and therefore decreases the CE. Figure 5 confirms this observation. The planar target is more effective than the droplet target for small and medium laser radiation intensities. The overheating reverses this situation for laser intensities higher than  $\sim 2.5 \times 10^{11}$  W/cm<sup>2</sup>.

At lower laser intensities, the plasma is not excessively overheated and the size of EUV area is larger for the planar geometry because of better plasma evolution and containment. The EUV radiation area produced by laser heating of intensity  $7 \times 10^{10}$  W/cm<sup>2</sup> is shown in Fig. 6. The most sig-

nificant EUV photon production zone is located around the spot center, in contrast to the previously described situation. At higher laser intensities, hydrodynamic plasma evolution moving away from the area of laser energy deposition/absorption prevents further plasma overheating in the system with the spherical configuration (Fig. 4). Therefore, the difference in CE for planar and spherical targets can be explained by the nature of hydrodynamic geometrical containment. Conditions for high plasma density with stable optimum temperature should be created to obtain the highest CE. The plasma temperature stability is provided by the balance between the incoming and escaping energy, i.e., laser energy absorption, radiation energy loss, and plasma expansion. The last term is mainly controlled by hydrodynamic and geometrical confinement.

These geometrical hydrodynamic effects control the plasma motion, i.e., limit and control the escaping plasma from the laser heating area and from the most productive EUV generation zone. In the case of the larger laser heating region, lower laser intensities are needed to create the efficient EUV production area because of the longer time of the plasma motion under the laser beam. The smaller laser irradiation spots produce opposite effects. As a result, the hydrodynamic confinement is believed to be the cause of the right shift of the maximum CE due to the decrease of the laser beam radius (see Fig. 7). This is a consequence of the hydrodynamic evolution where the plasma confinement can play an important role. The main effects to maximize EUV production are to create the right plasma density and temperature conditions with maximum size for the longest possible period of time.

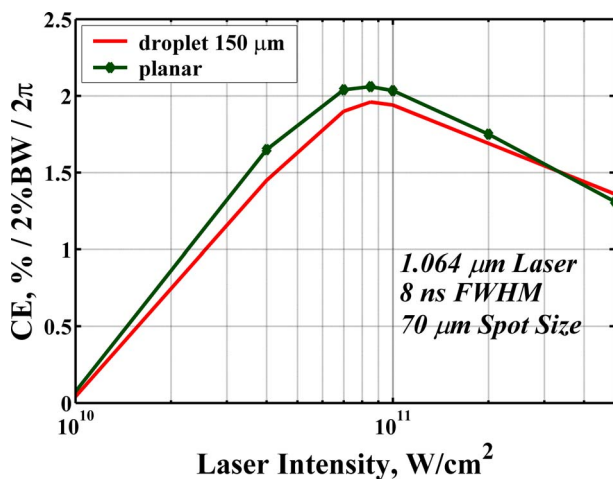


Fig. 5 Dependence of the conversion efficiency on laser intensity for both sphere and planar geometries.

#### 4 Conclusion

Enhanced integrated hydrodynamic, plasma, and photon transport models continue to be developed and implemented in the HEIGHTS computer package to simulate EUV emission in both laser- and discharge-produced plasma devices. The developed and enhanced models were used to analyze the influence of spatial hydrodynamic plasma evolution on the EUV radiation generation for pla-

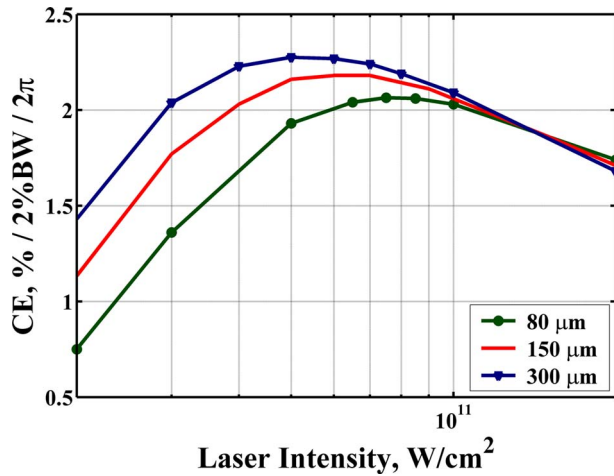


Fig. 7 Dependence of the conversion efficiency on laser intensity and beam spot size.

nar and spherical geometries of a tin target in LPP devices. The higher efficiency of a planar target in comparison to spherical geometry was explained due to better hydrodynamic geometrical containment of the heated plasma. A new Center for Materials under Extreme Environments (CMUXE) laboratory was recently established to conduct LPP experiments to benchmark HEIGHTS models for EUV photon production and the study of plasma debris effects on collector mirror reflectivity. Recent CMUXE experimental results for plasma production and laser conversion efficiency agree well with the HEIGHTS models.

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